

3 A LOW Vf Schottky Barrier Rectifier

DESCRIPTION

In Microsemi's new Powermite3® SMT package, these high efficiency ultrafast rectifiers offer the power handing capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies.

In addition to its size advantages, Powermite3® package features include a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly, and a unique locking tab acts as an integral heat sink. Its innovative design makes this device ideal for use with automatic insertion equipment.

ABSOLUTE MAXIMUM RATINGS AT 25° C

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

(UNLESS OTHERWISE SPECIFIED)						
Rating	Symbol	Value	Unit			
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V			
RMS Reverse Voltage	V _{R (RMS)}	28	V			
Average Rectified Output Current	Io	3	Α			
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on Rated Load @ T _c =100 °C	I _{FSM}	50	А			
Storage Temperature	T stg	-55 to +150	۰C			
Operating Temperature	Тор	-55 to +125	٥C			

THERMAL CHARACTERISTICS (UNLESS OTHERWISE SPECIFIED) Thermal Resistance °C/Watt Junction-to Bottom Rja (1) 2.5

(1) When Mounted on PC board with 2 ounce copper pattern.

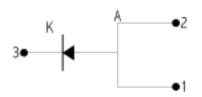


KEY FEATURES

- High power surface mount package.
- Guard Ring die construction for transient protection.
- Silicon Schottky rectifiers no reverse voltage recovery.
- Internal heat sink locking tabs
- Low forward voltage.
- Full metallic bottom eliminates flux entrapment
- Compatible with automatic insertion equipment
- Low profile-maximum height of 1mm supplied in 16 mm tape reel- 5000 units/ 13" reel.

APPLICATIONS/BENEFITS

- Switching and Regulating Power Supplies.
- Charge Pump Circuits.
- Reduces reverse recovery loss due to low I_{RM}.
- Small foot print 190 X 300 mils 1:1 Actual size



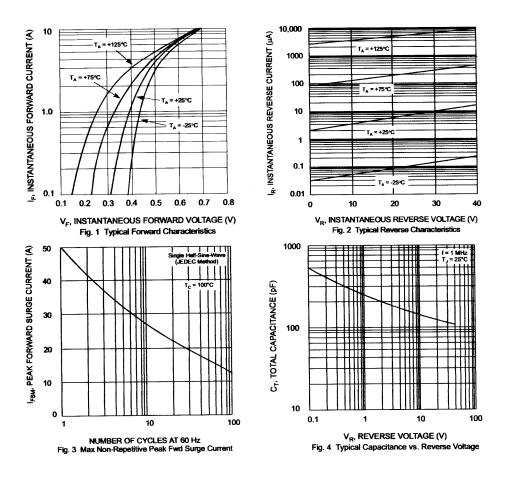
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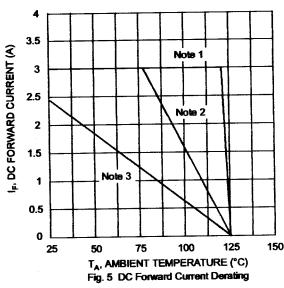
Parameter	Symbol	Conditions	Min	Тур.	Max	Units
				T		_
Forward Voltage (Note 1)		$I_F = 3 \text{ A}$, $T_j = 25 {}^{\circ}\text{C}$		0.46	0.50	
	\/	$I_F = 3 \text{ A}$, $T_i = 125 ^{\circ}\text{C}$		0.40	0.44	V
	V_{Fm}	$I_F = 3 \text{ A}$, $T_j = 125 ^{\circ}\text{C}$ $I_F = 6 \text{ A}$, $T_j = 25 ^{\circ}\text{C}$		0.57	0.61	V
		$I_F = 6 \text{ A}$, $T_i = 125 ^{\circ}\text{C}$		0.54	0.58	
Reverse Break Down Voltage		,				
(Note 1)	V_{BR}	$I_R = 0.5 \text{ mA}$	40			V
Reverse Current (Note1)		V _R = 40V, T _j = 25 °C		15	500	uA
,	I _m	V _R = 40V, T _i =100 °C		10	20	mA
		. ,				
Capacitance	Ст	$V_R = 4 \text{ V}; F = 1 \text{ MH}_Z$		180		pF

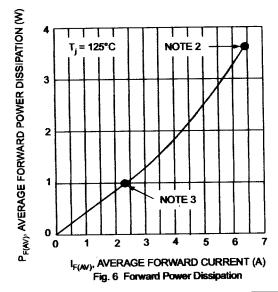
Note: 1 Short duration test pulse used to minimize self – heating effect.





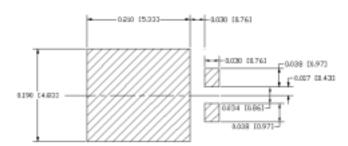
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Notes: 1. $T_A = T_{SOLDERING\ POINT}$, $R_{\Theta JS} = 3.4^{\circ}$ C/W $R_{\Theta sa} = 0^{\circ}$ C/W.

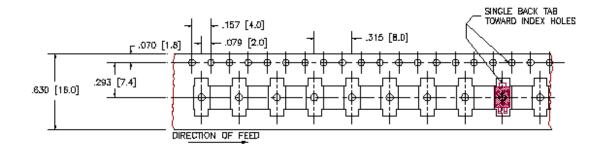
- 2. Device mounted on GETEK substrate, 2" x 2", 2 oz. copper , double-sided , cathode pad dimensions .075" x 1.0", anode pad dimensions 0.25" x 1.0". $R_{\Theta JA}$ in range of 20-40° C/W.
- 3. Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout $R_{\Theta JA}$ in range of 95 115° C/W.



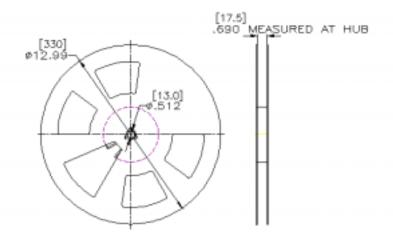


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16 mm TAPE



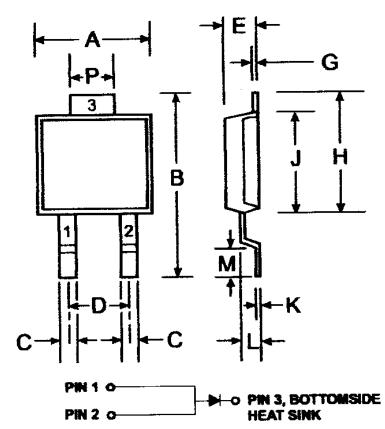
13 INCH REEL



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POWERMITE®3				
Dim	Min	Max		
A	4.03	4.09		
8	6.40	6.61		
С	.889 NOM			
D	1.83 NOM			
E	1.10	1.14		
G	.178 NOM			
Н	5.01	5.17		
J	4.37	4.43		
K	.178 NOM			
L	.71	.77		
M	.36	.46		
Р	1.73	1.83		
All Dimensions in mm				

Note: Pins 1 & 2 must be electrically connected at the printed circuit board.



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NOTES: